

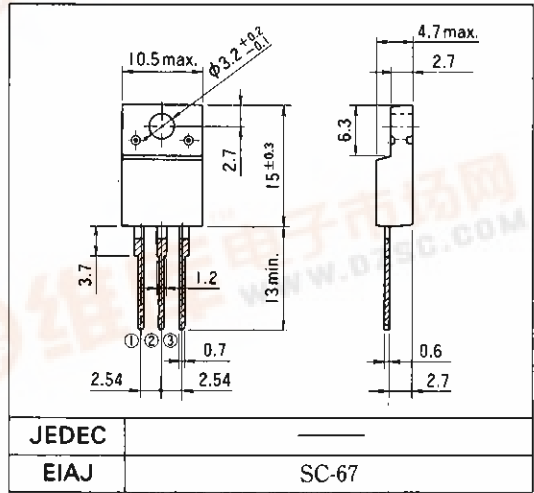
YG802C(N)09(10A)

富士小電力ダイオード

ショットキーバリアダイオード

SCHOTTKY BARRIER DIODE

外形寸法：Outline Drawings



特長：Features

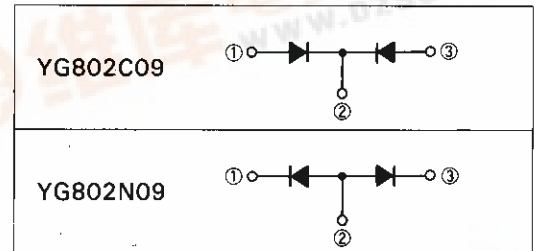
- 取り付け面が絶縁されたフルモールドタイプ
Insulated package by fully molding.
- 低 V_F
Low V_F
- スイッチングスピードが非常に速い
Super high speed switching.
- プレーナー技術による高信頼性
High reliability by planer design.

用途：Applications

- 高速電力スイッチング
High speed power switching.

電極接続

Connection Diagram



定格と特性：Maximum Ratings and Characteristics

絶対最大定格：Absolute Maximum Ratings

Items	Symbols	Conditions	Ratings	Units
ピーク繰り返し逆電圧 Repetitive Peak Reverse Voltage	V_{RRM}		90	V
ピーク非繰り返し逆電圧 Non-Repetitive Peak Reverse Voltage	V_{RSM}	$tw = 500ns, duty = 1/10$	100	V
平均出力電流 Average Output Current	I_O	方形波, $duty = 1/2, T_c = 87^\circ C$ Square wave	10*	A
サージ電流 Surge Current	I_{FSM}	正弦波 Sine wave 10ms	80	A
接合温度 Operating Junction Temperature	T_J		-40 ~ +125	$^\circ C$
保存温度 Storage Temperature	T_{stg}		-40 ~ +125	$^\circ C$

*センタータップ平均出力電流

*average forward current of centertap full wave connection

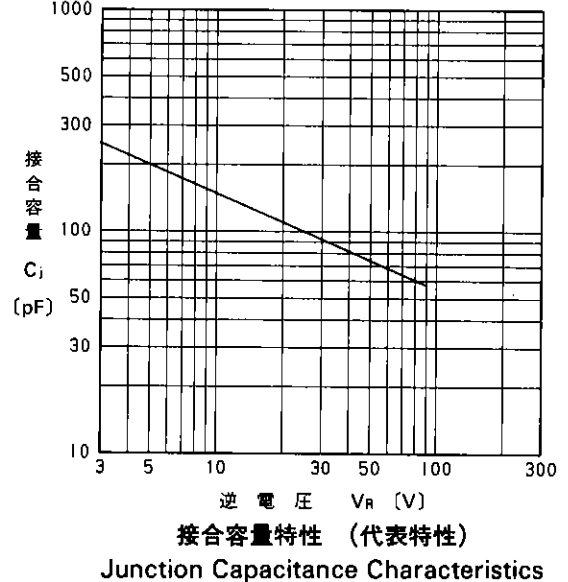
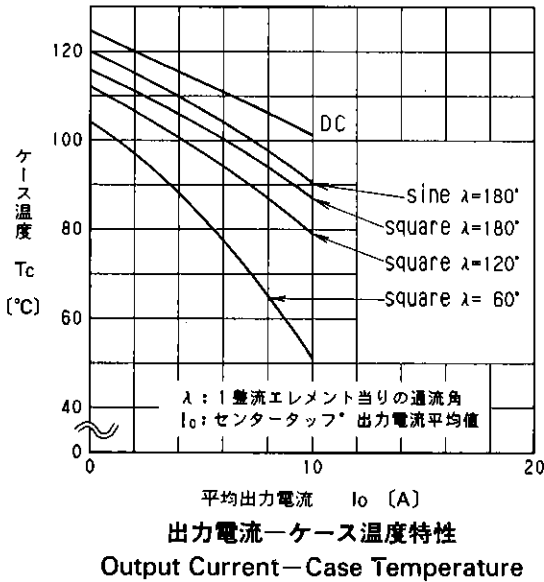
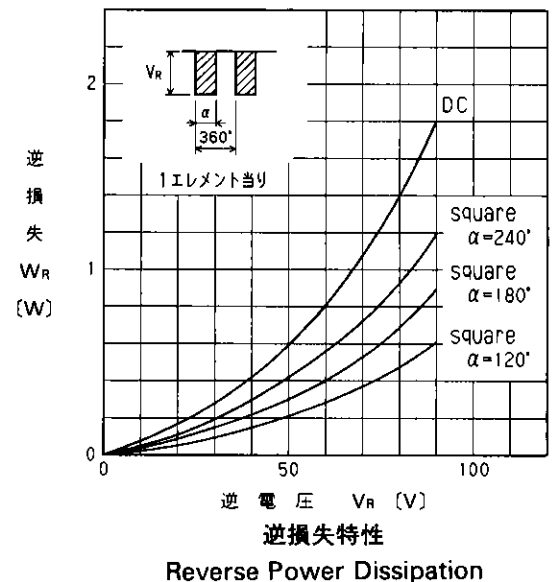
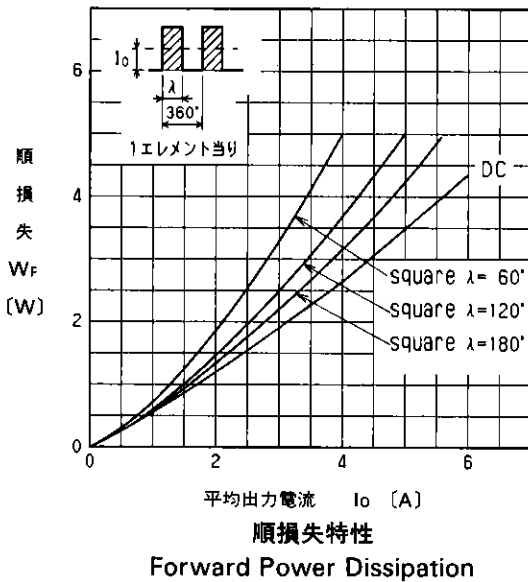
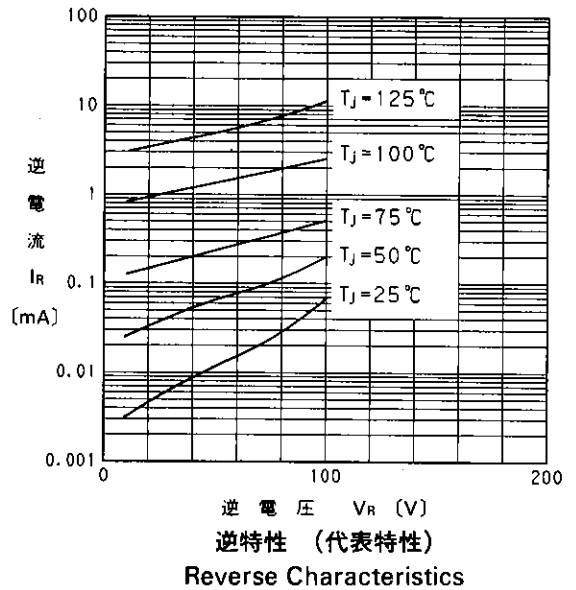
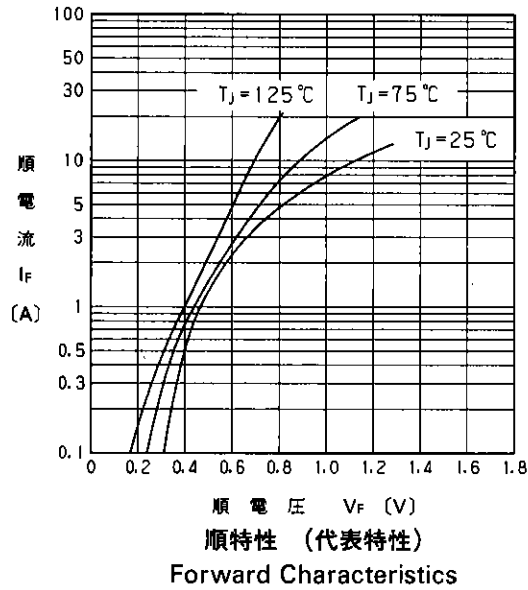
電気的特性(特に指定がない限り周囲温度 $T_a = 25^\circ C$ とする)

Electrical Characteristics ($T_a = 25^\circ C$ Unless otherwise specified)

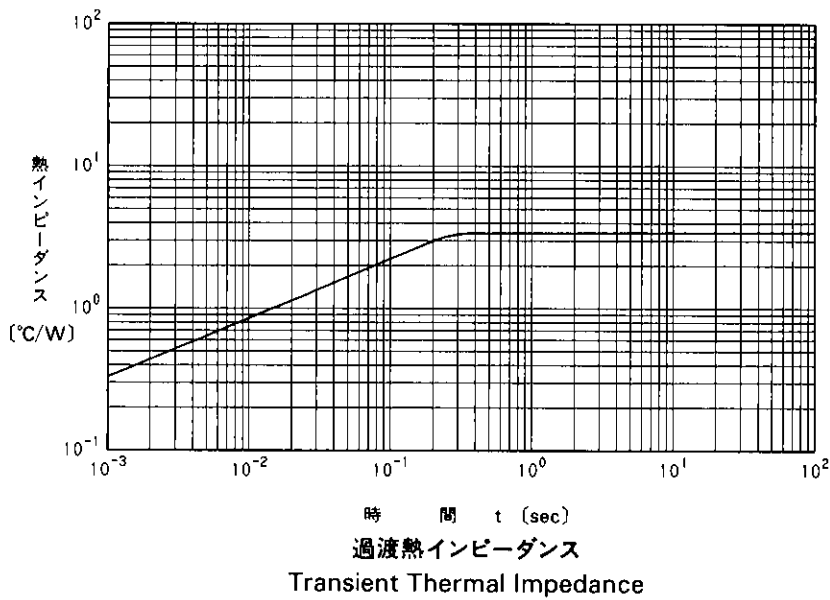
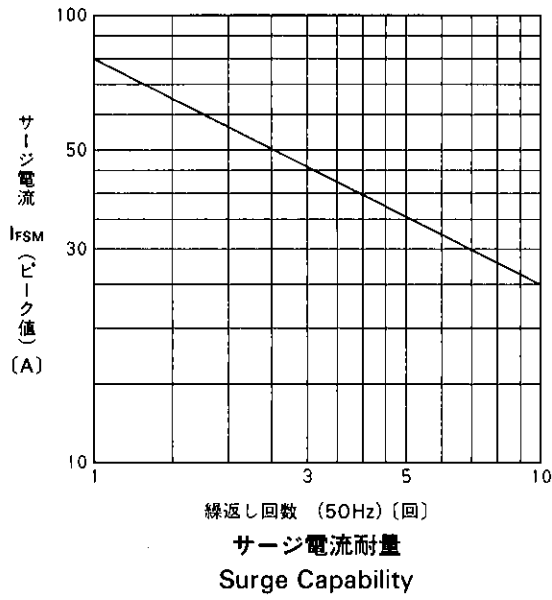
Items	Symbols	Conditions	Max.	Units
順電圧 Forward Voltage Drop	V_{FM}	$I_{FM} = 4A$	0.9	V
逆電流 Reverse Current	I_{RRM}	$V_R = V_{RRM}$	5	mA
熱抵抗 Thermal Resistance	$R_{th(j-c)}$	接合・ケース間 Junction to case	3.5	$^\circ C/W$



■特性曲線：Characteristics



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